

FCX717

12V PNP SILICON POWER (SWITCHING) TRANSISTOR IN SOT89

Features

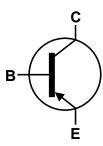
- BV_{CEO} = -12V
- I_C = -3.0A Continuous Current
- Low Saturation Voltage V_{CE(sat)} < -20mV @ -100mA
- $R_{sat} = 77m\Omega$ for a Low Equivalent On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

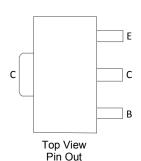
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ³
- Weight: 0.05 grams (Approximate)







Device Symbol



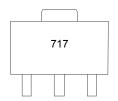
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
FCX717TA	Standard	717	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



717 = Product Type Marking Code



Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-12	V
Collector-Emitter Voltage	V _{CEO}	-12	V
Emitter-Base Voltage	V_{EBO}	-5	V
Continuous Collector Current	O_	-3	Α
Peak Pulse Collector Current	Ісм	-10	Α
Base Current	l _Β	-500	Α

Thermal Characteristics ($\textcircled{@} T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	1	W
Power Dissipation (Note 6)	P _D	2	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	-12	-35	_	V	$I_C = -100 \mu A$
Collector- Emitter Breakdown Voltage (Note 7)	BV_CEO	-12	-25	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	-8.5	_	V	$I_E = -100 \mu A$
Collector Cutoff Current	I _{CBO}	_	_	-100	nA	V _{CB} = -10V
Emitter Cutoff Current	I _{EBO}	_	_	-100	nA	V _{EB} = -4V
Collector Emitter Cutoff Current	I _{CES}	_	_	-100	nA	V _{CES} = -10V
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	_	-12 -110 -230	-20 -150 -320	mV	I_C = -0.1A, I_B = -10mA I_C = -1A, I_B = -10mA I_C = -3A, I_B = -50mA
Base-Emitter Saturation Voltage (Note 7)	$V_{BE(sat)}$	_	-0.92	-1.05	mV	$I_C = -3A$, $I_B = -50mA$
Base-Emitter Turn-On Voltage (Note 7)	$V_{BE(on)}$	_	-0.85	-1.0	mV	$I_C = -3A$, $V_{CE} = -2V$
DC Current Gain (Note 7)	h_{FE}	300 300 160 60 45	475 450 240 100 70	_	_	I _C = -10mA, V _{CE} = -2V I _C = -0.1A, V _{CE} = -2V I _C = -3A, V _{CE} = -2V I _C = -8A, V _{CE} = -2V I _C = -10A, V _{CE} = -2V
Transitional frequency	f_{T}	80	110	_	MHz	I_{C} = -50mA, V_{CE} = -10V f = 100MHz
Output Capacitance	C _{obo}	_	21	30	pF	V _{CB} = -10V, f = 1MHz
Switching Time	t _{on} t _{off}		70 130	_	ns	$I_C = -2A$, $V_{CC} = -6V$, $I_{B1} = -I_{B2} = 50mA$

Notes:

^{5.} For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.

^{6.} Same as note (5), except the device is mounted on 40mm x 40mm x 0.6mm single sided 1oz weight copper.

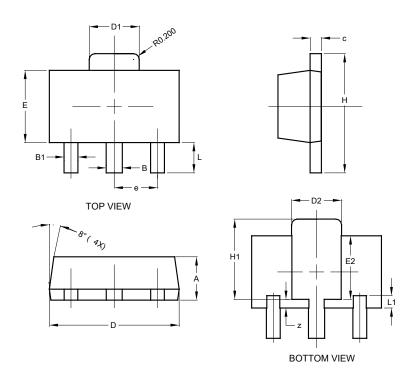
^{7.} Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

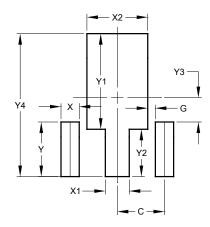


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

SOT89



Dimensions	Value (in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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